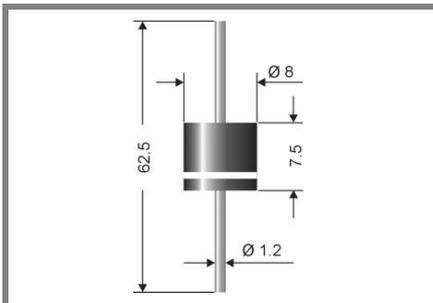


# P 600 A...P 600 S



## Axial lead diode

## Standard silicon rectifier diodes

### P 600 A...P 600 S

**Forward Current: 6 A**

**Reverse Voltage: 50 to 1200 V**

### Features

- Max. solder temperature : 260°C
- Plastic material has UL classification 94V-0

### Mechanical Data

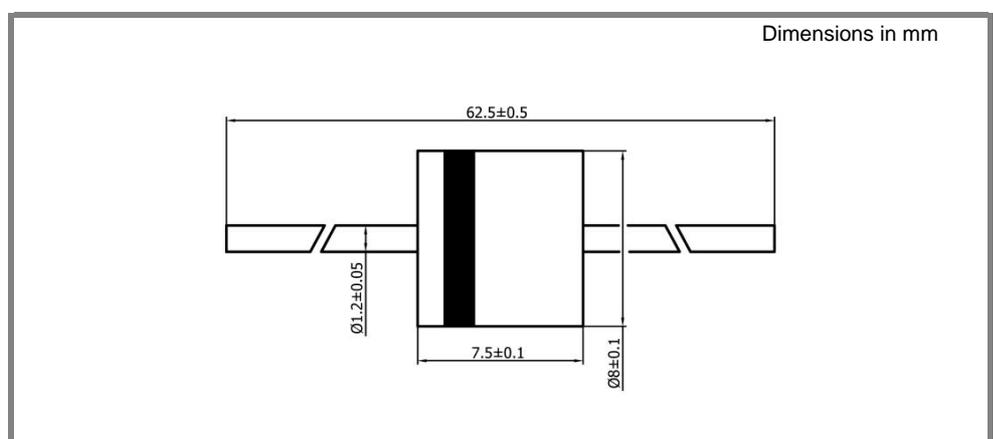
- Plastic case 8 x 7.5 [ mm ]
- Weight approx.: 1.5 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 500 pieces per ammo or 1000 pieces per reel

- 1) Valid, if leads are kept at  $T_A$  at a distance of 10 mm from case
- 2)  $I_F = 5A$ ,  $T_j = 25^\circ C$
- 3)  $T_A = 25^\circ C$
- 4) Thermal resistance from junction to lead/terminal at a distance 0 mm from case
- 5) Max. junction temperature  $T_j \leq 185^\circ C$  in reverse mode  $V_R = 50\% V_{RRM}$ ,  $T_j \leq 200^\circ C$  in bypass mode

| Type    | Repetitive peak reverse voltage<br>$V_{RRM}$<br>V | Surge peak reverse voltage<br>$V_{RSM}$<br>V | Max. reverse recovery time<br>$I_F = -A$<br>$I_R = -A$<br>$I_{RR} = -A$<br>$t_{rr}$<br>ns | Max. forward voltage<br>$V_F^{(2)}$ |
|---------|---|--|---|-------------------------------------|
| P 600 A | 50  | 50   | -   | 1,0                                 |
| P 600 B | 100   | 100  | -   | 1,0                                 |
| P 600 D | 200   | 200  | -   | 1,0                                 |
| P 600 G | 400   | 400  | -   | 1,0                                 |
| P 600 J | 600   | 600  | -   | 1,0                                 |
| P 600 K | 800   | 800  | -   | 1,0                                 |
| P 600 M | 1000  | 1000   | -   | 1,0                                 |
| P 600 S | 1200  | 1200   | -   | 1,0                                 |

| Absolute Maximum Ratings |  | $T_A = 25^\circ C$ , unless otherwise specified     |                  |
|--------------------------|--|---|------------------|
| Symbol                   | Conditions   | Values  | Units            |
| $I_{FAV}$                | Max. averaged fwd. current, R-load, $T_A = 50^\circ C$ <sup>1)</sup> | 6   | A                |
| $I_{FRM}$                | Repetitive peak forward current $f > 15 Hz$ <sup>1)</sup>            | 60  | A                |
| $I_{FSM}$                | Peak forward surge current 50 Hz half sinus-wave <sup>3)</sup>       | 400   | A                |
| $i^2t$                   | Rating for fusing, $t < 10 ms$ <sup>3)</sup>                         | 800   | A <sup>2</sup> s |
| $R_{thA}$                | Max. thermal resistance junction to ambient <sup>1)</sup>            |   | K/W              |
| $R_{thL}$                | Max. thermal resistance junction to terminals <sup>4)</sup>          | 3,5   | K/W              |
| $T_j$                    | Operating junction temperature                                       | -50...+175 ( $T_j \leq 200^\circ C$ <sup>5)</sup> ) | °C               |
| $T_s$                    | Storage temperature  | -50...+175  | °C               |

| Characteristics |   | $T_A = 25^\circ C$ , unless otherwise specified |       |
|-----------------|---|---|-------|
| Symbol          | Conditions  | Values  | Units |
| $I_R$           | Maximum leakage current, $T_j = 25^\circ C$ ; $V_R = V_{RRM}$   | <25   | µA    |
|                 | $T_j = ^\circ C$ ; $V_R = V_{RRM}$  |   |       |
| $C_j$           | Typical junction capacitance (at MHz and applied reverse voltage of V)                                      | -   | pF    |
| $Q_{rr}$        | Reverse recovery charge ( $U_R = V$ ; $I_F = A$ ; $di_F/dt = A/ms$ )  | -   | µC    |
| $E_{RSM}$       | Non repetitive peak reverse avalanche energy ( $I_R = mA$ ; $T_j = ^\circ C$ ; inductive load switched off) | -   | mJ    |



case: 8 x 7,5 [ mm ]

